Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

6.828 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-9

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.250 inches

Thread Size:

0.750 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

300.0 repetitive peak reverse voltage

Current Rating Per Characteristic:

160.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

190.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 uninsulated wire lead w/terminal lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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